Product data sheet

1. General description

Silicon Carbide Schottky diode in a SMB plastic package, designed for high frequency switched-mode power supplies.





2. Features and benefits

- · Highly stable switching performance
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

3. Applications

- · Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values			Unit	
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage		650		V		
$I_{F(AV)}$	average forward current	δ = 0.5; square-wave pulse; $T_{lead} \le 43$ °C; Fig. 1; Fig. 2; Fig. 3		3		А	
T _j	junction temperature		175		°C		
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	I _F = 3 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.5	1.7	V
		I _F = 3 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.72	2	V
Dynamic	characteristics				,		
Q_r	recovered charge	$I_F = 3 \text{ A}; dI_F/dt = 500 \text{ A/}\mu\text{s}; V_R = 400 \text{ V};$ $T_i = 25 \text{ °C}; Fig. 7$		-	10	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		K 14 V
2	A	anode	1 2	K ⊢ ├ A 001aaa020

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WNSC2D03650MB	SMB	WNSC2D03650MBJ	Reel	3000	SMB	20-Feb-2017

7. Marking

Table 4. Marking codes

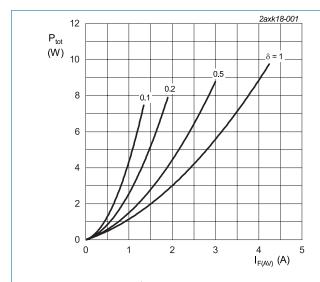
Type number	Marking codes
WNSC2D03650MB	2365ES

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		650	V
V_{RWM}	crest working reverse voltage		650	V
V_R	reverse voltage	DC	650	V
I _{F(AV)}	average forward current	$δ$ = 0.5; square-wave pulse; $T_{lead} \le 43$ °C; Fig. 1; Fig. 2; Fig. 3	3	А
I _{FRM}	repetitive peak forward current	$δ$ = 0.5; t_p = 25 μs; T_{lead} ≤ 43 °C; square-wave pulse	6	А
I _{FSM}	non-repetitive peak	$t_p = 10 \text{ ms}; T_{j(init)} = 25 \text{ °C}; \text{ sine-wave pulse}$	18	А
	forward current	t_p = 10 µs; $T_{j(init)}$ = 25 °C; square-wave pulse	235	А
l ² t	I ² t for fusing	sine-wave pulse; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$	1.62	A ² s
T _{stg}	storage temperature		-55 to 175	°C
T _j	junction temperature		175	°C



$$\begin{split} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_o &= 0.789 \text{ V; R}_s = 0.3560 \text{ } \Omega \end{split}$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

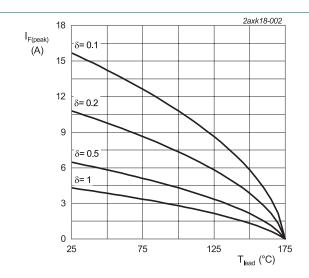
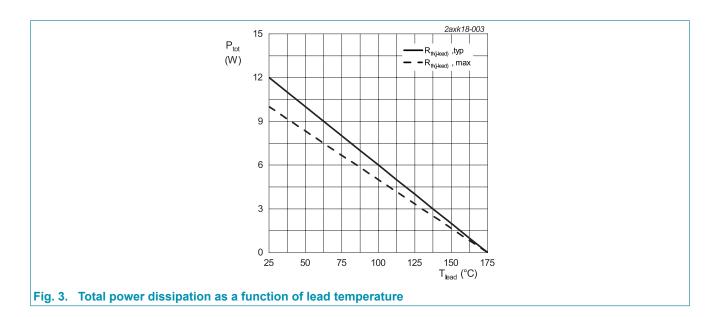


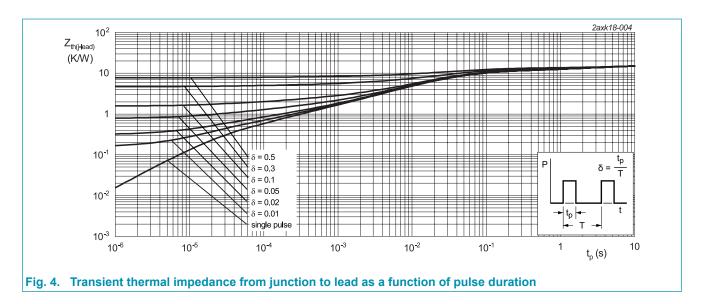
Fig. 2. Current derating as a function of lead temperature



9. Thermal characteristics

Table 6. Thermal characteristics

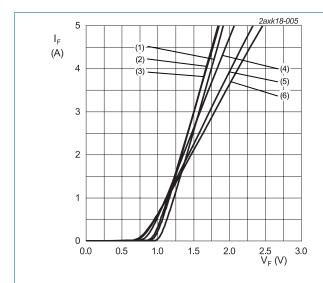
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-lead)}}$	thermal resistance from junction to lead	<u>Fig. 4</u>	-	12.5	15	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	90	-	K/W



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _F	forward current	I _F = 3 A; T _j = 25 °C; <u>Fig. 5</u>	-	1.5	1.7	V
		I _F = 3 A; T _j = 150 °C; <u>Fig. 5</u>	-	1.72	2	V
		I _F = 3 A; T _j = 175 °C; <u>Fig. 5</u>	-	1.8	2.1	V
I _R re	reverse current	V _R = 650 V; T _j = 25 °C; <u>Fig. 6</u>	-	0.2	20	μA
		V _R = 650 V; T _j = 175 °C; <u>Fig. 6</u>	-	10	200	μA
Dynamic	characteristics					
Q _r	recovered charge	$I_F = 3 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	10	-	nC
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C	-	130	-	pF
		f = 1 MHz; V _R = 300 V; T _j = 25 °C	-	17	-	pF
		f = 1 MHz; V _R = 600 V; T _j = 25 °C	-	15	-	pF
E _{as}	non-repetitive avalanche energy	I _R = 2.7 A; L = 5 mH; T _{j(init)} = 25 °C	18	-	-	mJ



 $V_0 = 0.789 \text{ V}; R_s = 0.3560 \Omega$

(1) T_i = -55 °C; typical values

(2) T_i = 0 °C; typical values

(3) T_i = 25 °C; typical values

(4) T_j = 100 °C; typical values (5) T_j = 150 °C; typical values (6) T_j = 175 °C; typical values

Fig. 5. Forward current as a function of forward voltage; typical values

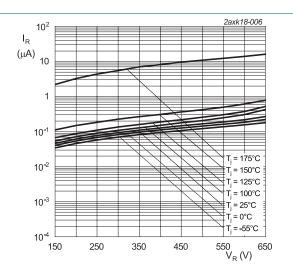


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value

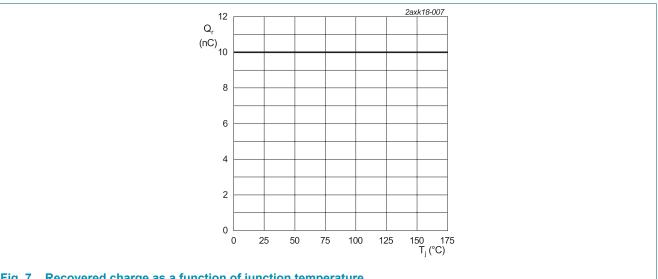
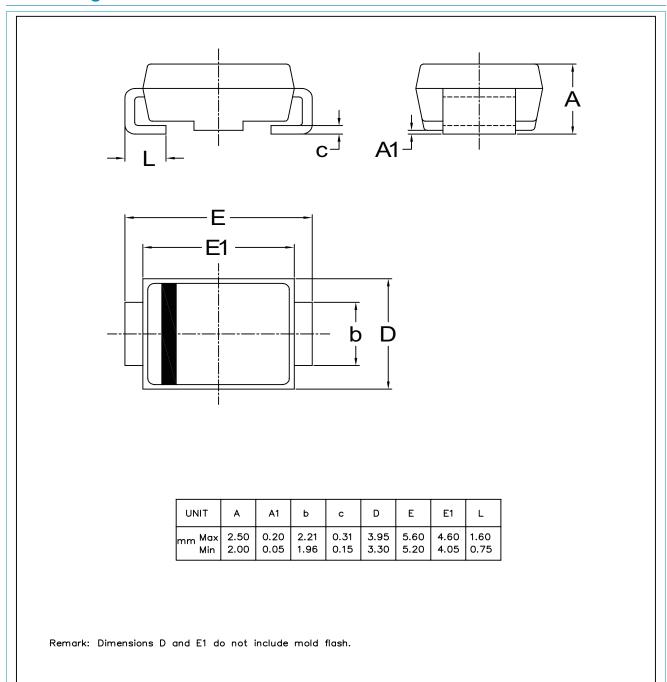


Fig. 7. Recovered charge as a function of junction temperature

11. Package outline



12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Date of release: 16 December 2021

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